

To the Honorable Commissioner of, 102326267 attached original documents or copy thereof.

## 1 Name of conveying party(ies):

Chao-Hsiang Yang  
Chun-Ming Su

12-18-02

## 2 Name and address of receiving party(ies):

Taiwan Semiconductor Manufacturing Co. Ltd.  
No. 121 Park Avenue 3  
Science-Based Industrial Park  
Hsin-Chu, Taiwan, R.O.C.

## 3 Nature of conveyance:

☒ Assignment ☐ Merger  
☐ Security Agreement ☐ Change of Name☐ Other:Execution Date: November 16, 2002Additional name(s) & address(es) attached ☐ Yes ☒ NoJ1036 U.S. PTO  
10/323350

12/18/02

## 4 Application number(s) or patent number(s):

If this document is being filed together with a new application, the execution date of the application is: 11-16-02

A. Patent Application No(s).

10,323,350

B. Patent No(s)

Additional numbers attached? ☐ Yes ☒ No

## 5 Name and address of party to whom correspondence concerning document should be mailed:

RANDY W. TUNG  
Tung & Associates  
838 W. Long Lake Road  
Suite 120  
Bloomfield Hills, Michigan 48302

## 6 Total number of applications and patents involved:

1

## 7 Total fee (37 CFR 3.41)

\$40.00

☐ Enclosed  
☒ Authorized to charge credit card (w/filing fee)

## 8 Deposit Account Number: 50-0484

(Attach duplicate copy of this page if paying by deposit account)

12/23/2002 RMEBRAHT 00000062 10323350

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## 9 Statement and signature.

*To the best of my knowledge and belief, the foregoing information is true and correct and any attached copy is a true copy of the original document.*

Randy W. Tung

Name of Person Signing  
Registration No. 31,311

Signature

December 18, 2002

Date

Total number of pages including cover sheet, attachments, and document: 3Mail documents to be recorded with required cover sheet information to:  
Commissioner of Patents & Trademarks, Box Assignments  
Washington, D.C. 20231

ASSIGNMENT

WHEREAS, we, CHAO-HSIANG YANG and CHUN-MING SU have invented  
certain improvements in

METHOD OF FORMING A METAL FUSE ON SEMICONDUCTOR DEVICES

for which we are about to make application for Letters Patent of the United States; and

WHEREAS, TAIWAN SEMICONDUCTOR MANUFACTURING CO., LTD. of  
No. 121, Park Avenue 3, Science-Based Industrial Park, Hsin-Chu, Taiwan, R.O.C, is desirous of  
acquiring the entire right, title and interest in and to said invention;

NOW, THEREFORE, in consideration of One Dollar (\$1.00) and other good and  
valuable consideration, the receipt of which is hereby acknowledged, we, CHAO-HSIANG YANG  
and CHUN-MING SU, by these presents, do hereby sell, assign and transfer unto the said  
corporation and its assigns, for the territory of the United States of America and all foreign countries,  
the entire right, title and interest, including all priority rights under the International Convention  
associated with each country of the Union, in and to said invention as described in the patent  
application executed by us on the 16<sup>th</sup> and 25th day of November, 2002, preparatory to

obtaining Letters Patent of the United States thereon, and in and to said application and any Letters Patent that may be granted in pursuance of said application and any divisional, continuation or continuation-in-part application thereof, and in and to any reissue of any such patent, and in and to any patent applications which may be filed on said invention in countries foreign to the United States and any Letters Patent granted thereon.

We further authorize said corporation to apply for foreign patents on said invention in its own name or through its designees, including subsidiaries, related companies or assignees, under the International Convention or otherwise, and we further agree to execute all papers, including those required for the United States and foreign applications, and to perform such other proper acts as said corporation or its designees the rights herein assigned.

*Chao-Hsiang Yang*  
CHAO-HSIANG YANG

*Chun-Ming Su*  
CHUN-MING SU

**TUNG & ASSOCIATES**  
**838 W. Long Lake Road**  
**Suite 120**  
**Bloomfield Hills, Michigan 48302**